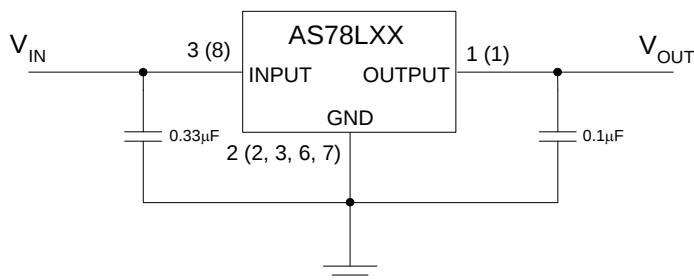
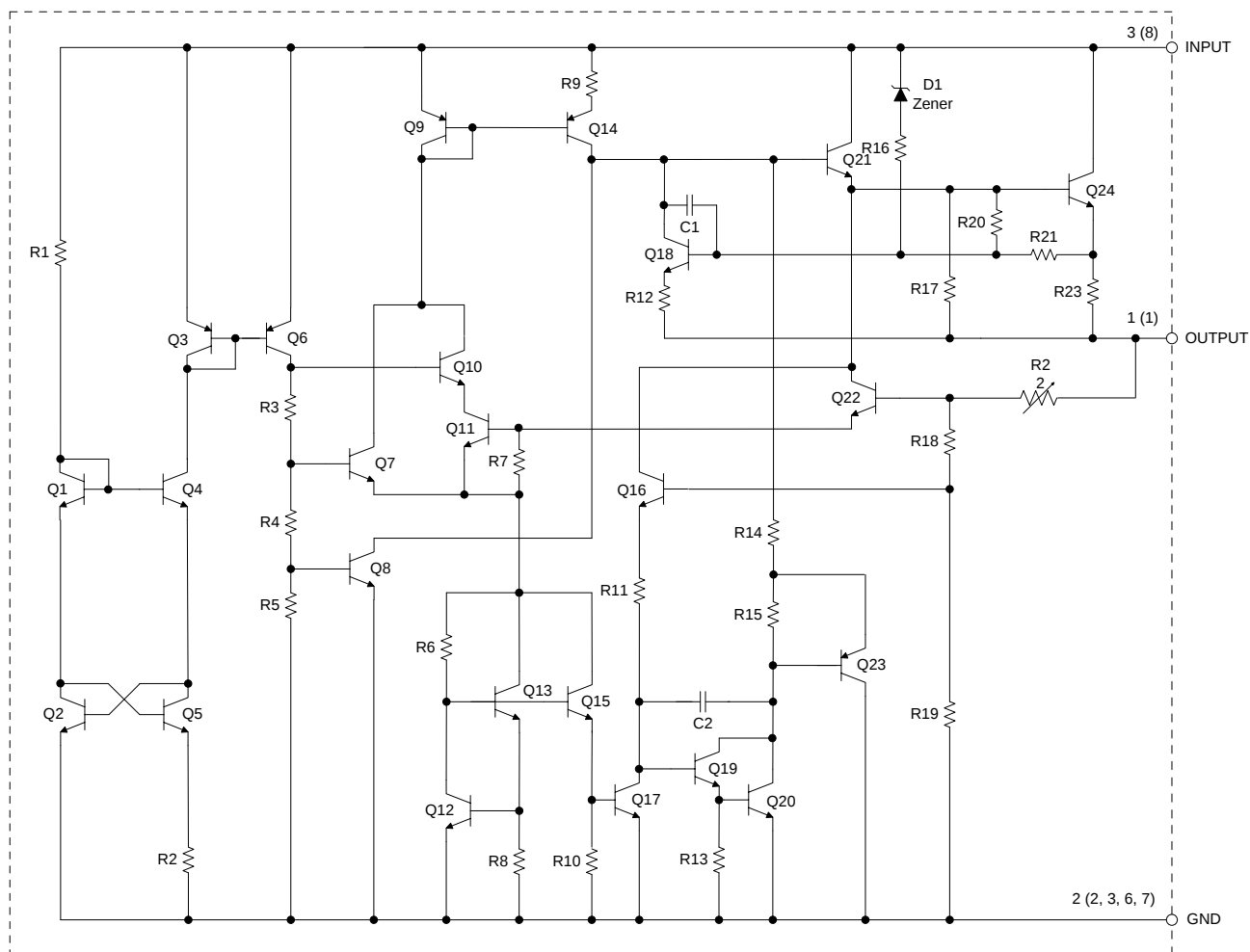


Typical Applications Circuit



A (B)
A for 3-pin B for 8-pin

Functional Block Diagram



A (B)
A for 3-pin B for 8-pin

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Rating	Unit
V_{IN}	Input Voltage	36	V
T_J	Operating Junction Temperature	150	°C
T_{LEAD}	Lead Temperature (Soldering, 10sec)	260	°C
P_D	Power Dissipation	750	mW
T_{STG}	Storage Temperature Range	-65 to +150	°C
θ_{JA}	Thermal Resistance	TO-92	+180
ESD	ESD (Human Body Model)	2000	V
ESD	ESD (Machine Model)	200	V

Note. 1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V_{IN}	Input Voltage	AS78L05	30	V
		AS78L12	36	
		AS78L15	36	
T_J	Operating Junction Temperature Range	-40	+125	°C

Electrical Characteristics

AS78L05 (@ $V_{IN} = 10V$, $I_{OUT} = 40mA$, $C_{IN} = 0.33\mu F$, $C_{OUT} = 0.1\mu F$, $T_J = +25^\circ C$, **Bold** typeface applies over $-40^\circ C \leq T_J \leq +125^\circ C$, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{OUT}	Output Voltage		4.8	5.0	5.2	V
		$7V \leq V_{IN} \leq 20V$, $1mA \leq I_{OUT} \leq 100mA$, $P_D \leq 0.75W$	4.75		5.25	
V_{RLINE}	Line Regulation	$7V \leq V_{IN} \leq 20V$		8	150	mV
V_{RLOAD}	Load Regulation	$1mA \leq I_{OUT} \leq 100mA$		10	60	mV
I_Q	Quiescent Current			3	5.5	mA
ΔI_Q	Quiescent Current Change	$8V \leq V_{IN} \leq 20V$			1.5	mA
		$1mA \leq I_{OUT} \leq 40mA$			0.1	
PSRR	Ripple Rejection	$f = 120Hz$, $8V \leq V_{IN} \leq 18V$	47	62		dB
V_{DROP}	Dropout Voltage	$I_{OUT} = 40mA$		1.7	2.0	V
		$I_{OUT} = 100mA$		1.8	2.3	
N_O	Output Noise Voltage	$10Hz \leq f \leq 100kHz$ (Note 2)		40		μV
$\Delta V_{OUT}/\Delta T$	Output Voltage Temperature Coefficient	$I_{OUT} = 5mA$		0.42		mV/°C
$(\Delta V_{OUT}/V_{OUT})/\Delta T$				84		ppm/°C
θ_{JC}	Thermal Resistance	TO-92		40		°C/W
		SOT-89		28.3		
		SOIC-8		62		

Note: 2. 0.01 μF minimum load capacitance is recommended to limit high frequency noise.

Electrical Characteristics (cont.)

AS78L05C (@ $V_{IN} = 10V$, $I_{OUT} = 40mA$, $C_{IN} = 0.33\mu F$, $C_{OUT} = 0.1\mu F$, $T_J = +25^\circ C$, **Bold** typeface applies over $-40^\circ C \leq T_J \leq +125^\circ C$, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{OUT}	Output Voltage		5.0		5.1	V
V_{RLINE}	Line Regulation	$7V \leq V_{IN} \leq 20V$		8	150	mV
V_{RLOAD}	Load Regulation	$1mA \leq I_{OUT} \leq 100mA$		10	60	mV
I_Q	Quiescent Current			3	5.5	mA
ΔI_Q	Quiescent Current Change	$8V \leq V_{IN} \leq 20V$			1.5	mA
		$1mA \leq I_{OUT} \leq 40mA$			0.1	
PSRR	Ripple Rejection	$F = 120Hz$, $8V \leq V_{IN} \leq 18V$	47	62		dB
V_{DROP}	Dropout Voltage	$I_{OUT} = 40mA$		1.7		V
		$I_{OUT} = 100mA$		1.8		
N_O	Output Noise Voltage	$10Hz \leq f \leq 100kHz$ (Note 2)		40		μV
$\Delta V_{OUT}/\Delta T$	Output Voltage Temperature Coefficient	$I_{OUT} = 5mA$		0.42		mV/ $^\circ C$
$(\Delta V_{OUT}/V_{OUT})/\square \Delta T$				84		ppm/ $^\circ C$
θ_{JC}	Thermal Resistance	TO-92		40		$^\circ C/W$
		SOT-89		28.3		
		SOIC-8		62		

Note: 2. 0.01 μF minimum load capacitance is recommended to limit high frequency noise.

Electrical Characteristics (cont.)

AS78L12 (@ $V_{IN} = 19V$, $I_{OUT} = 40mA$, $C_{IN} = 0.33\mu F$, $C_{OUT} = 0.1\mu F$, $T_J = +25^\circ C$, **Bold** typeface applies over $-40^\circ C \leq T_J \leq +125^\circ C$, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{OUT}	Output Voltage		11.5	12.0	12.5	V
		$14.5V \leq V_{IN} \leq 27V$, $1mA \leq I_{OUT} \leq 100mA$, $P_D \leq 0.75W$	11.4		12.6	
V_{RLINE}	Line Regulation	$14.5V \leq V_{IN} \leq 27V$		20	250	mV
V_{RLOAD}	Load Regulation	$1mA \leq I_{OUT} \leq 100mA$		20	100	mV
I_Q	Quiescent Current			3	6	mA
ΔI_Q	Quiescent Current Change	$16V \leq V_{IN} \leq 27V$			1.5	mA
		$1mA \leq I_{OUT} \leq 40mA$			0.1	
PSRR	Ripple Rejection	$f = 120Hz$, $15V \leq V_{IN} \leq 25V$	37	42		dB
V_{DROP}	Dropout Voltage	$I_{OUT} = 40mA$		1.7		V
		$I_{OUT} = 100mA$		1.8		
N_O	Output Noise Voltage	$10Hz \leq f \leq 100kHz$ (Note 2)		80		μV
$\Delta V_{OUT}/\Delta T$	Output Voltage Temperature Coefficient	$I_{OUT} = 5mA$		1		mV/ $^\circ C$
$(\Delta V_{OUT}/V_{OUT})/\square \Delta T$				84		ppm/ $^\circ C$
θ_{JC}	Thermal Resistance	TO-92		40		$^\circ C/W$
		SOT-89		28.3		
		SOIC-8		62		

Note: 2. 0.01 μF minimum load capacitance is recommended to limit high frequency noise.

Electrical Characteristics (cont.)

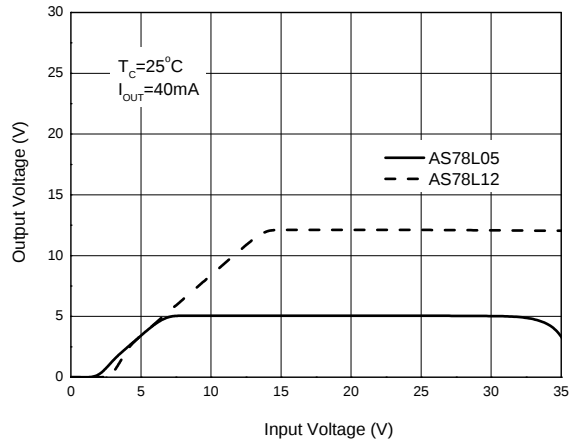
AS78L15 (@ $V_{IN} = 23V$, $I_{OUT} = 40mA$, $C_{IN} = 0.33\mu F$, $C_{OUT} = 0.1\mu F$, $T_J = +25^\circ C$, **Bold** typeface applies over $-40^\circ C \leq T_J \leq +125^\circ C$, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{OUT}	Output Voltage		14.4	15.0	15.6	V
		$17.5V \leq V_{IN} \leq 30V$, $1mA \leq I_{OUT} \leq 100mA$, $P_D \leq 0.75W$	14.25		15.75	
V_{RLINE}	Line Regulation	$17.5V \leq V_{IN} \leq 30V$		25	250	mV
V_{RLOAD}	Load Regulation	$1mA \leq I_{OUT} \leq 100mA$		25	150	mV
I_Q	Quiescent Current			3	6	mA
ΔI_Q	Quiescent Current Change	$20V \leq V_{IN} \leq 30V$			1.5	mA
		$1mA \leq I_{OUT} \leq 40mA$			0.1	
PSRR	Ripple Rejection	$f = 120Hz$, $18.5V \leq V_{IN} \leq 28.5V$	34	39		dB
V_{DROP}	Dropout Voltage	$I_{OUT} = 40mA$		1.7		V
		$I_{OUT} = 100mA$		1.8		
N_O	Output Noise Voltage	$10Hz \leq f \leq 100kHz$ (Note 2)		90		μV
$\frac{\Delta V_{OUT}}{\Delta T}$	Output Voltage Temperature Coefficient	$I_{OUT} = 5mA$		1.25		mV/ $^\circ C$
$(\frac{\Delta V_{OUT}}{V_{OUT}}) / \Delta T$				84		ppm/ $^\circ C$
θ_{JC}	Thermal Resistance	TO-92		40		$^\circ C/W$
		SOT-89		28.3		
		SOIC-8		62		

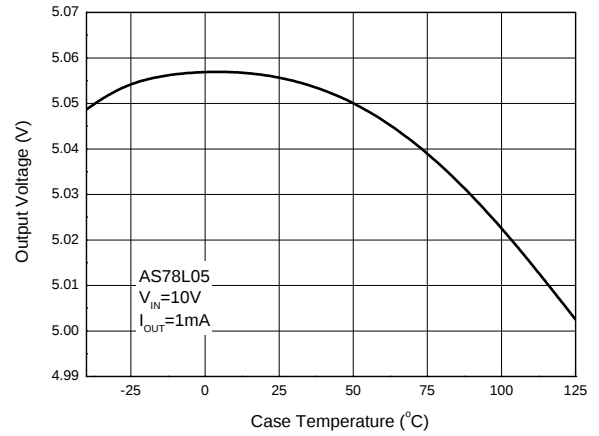
Note: 2. 0.01 μF minimum load capacitance is recommended to limit high frequency noise.

Performance Characteristics

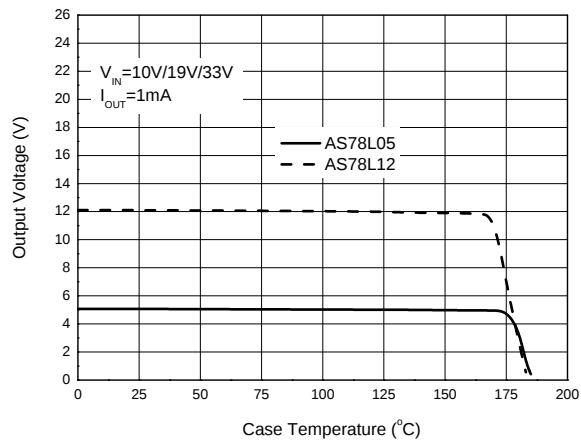
Output Voltage vs. Input Voltage



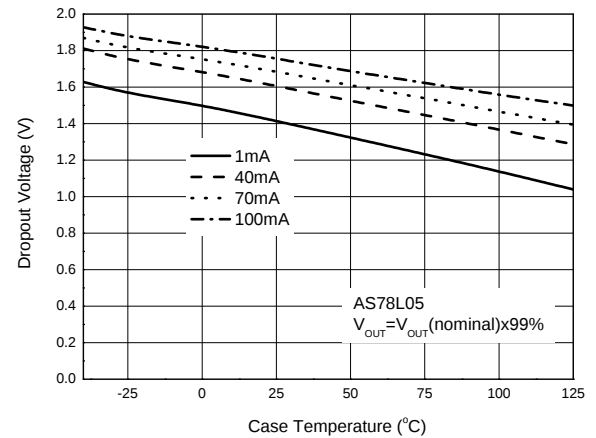
Output Voltage vs. Case Temperature



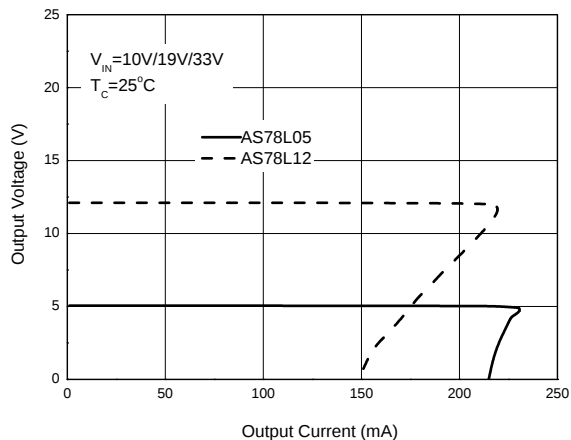
Over Temperature Protection



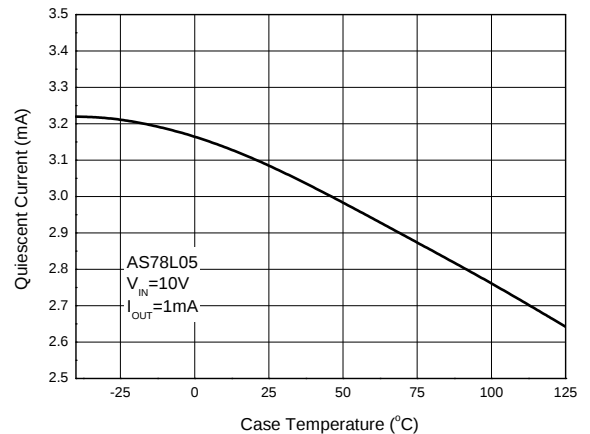
Dropout Voltage vs. Case Temperature



Output Voltage vs. Output Current

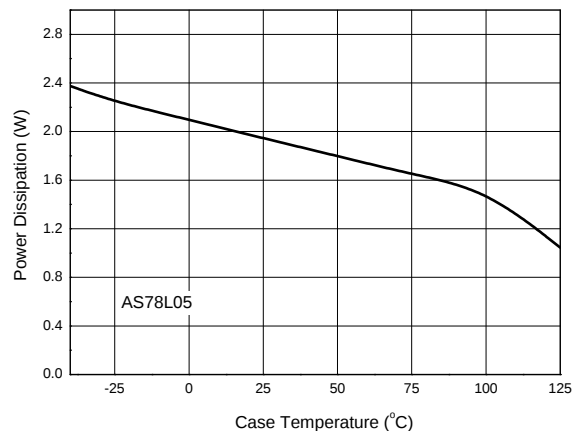


Quiescent Current vs. Case Temperature

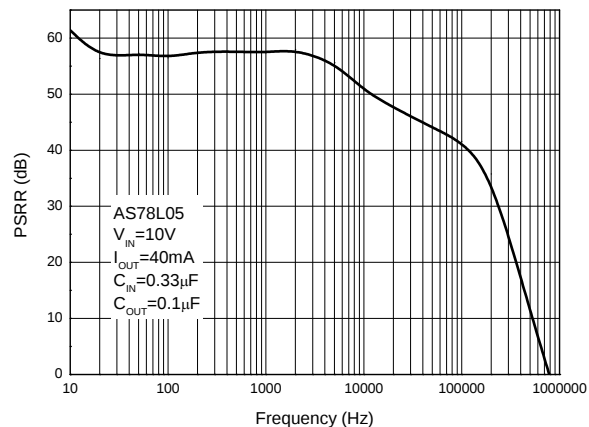


Performance Characteristics (cont.)

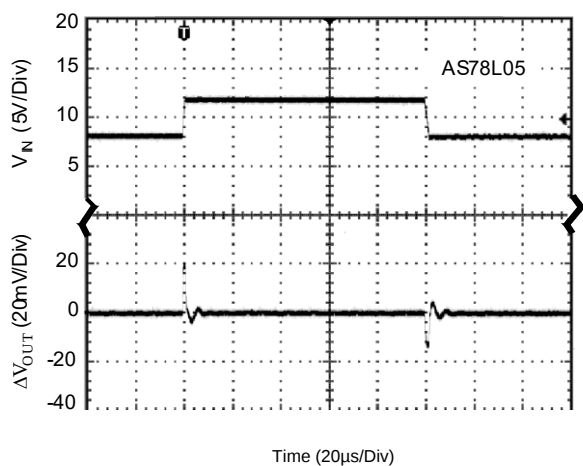
Power Dissipation vs. Case Temperature



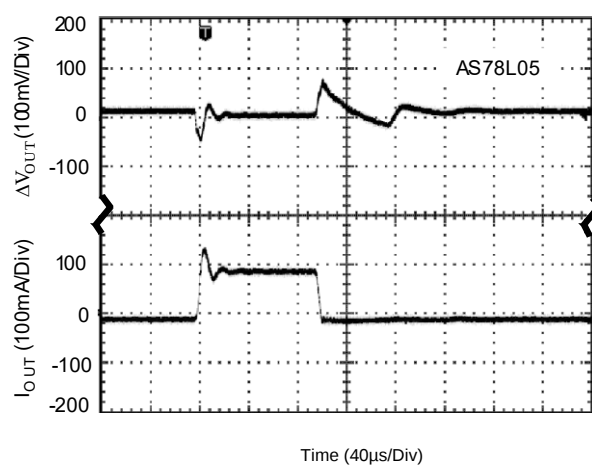
PSRR vs. Frequency



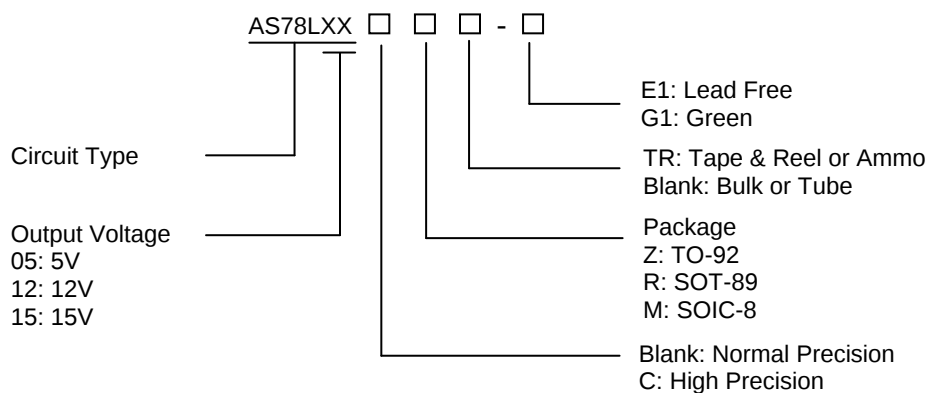
Line Transient
(Conditions: $I_{OUT}=40mA$, $C_{IN}=0.33\mu F$, $C_{OUT}=0.1\mu F$)



Load Transient
(Conditions: $V_{IN}=10V$, $C_{IN}=0.33\mu F$, $C_{OUT}=0.1\mu F$)



Ordering Information

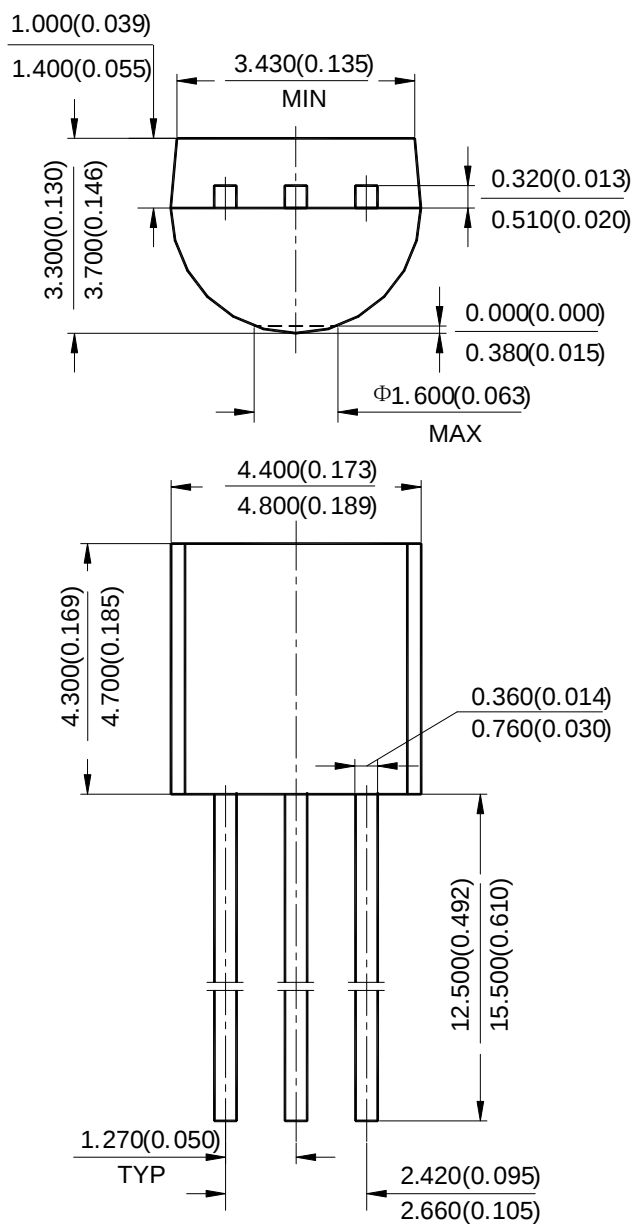


Package	Temperature Range	Part Number		Marking ID		Packing Type
		Lead Free	Green	Lead Free	Green	
TO-92	-40 to 125°C	AS78L05Z-E1	AS78L05Z-G1	AS78L05Z-E1	AS78L05Z-G1	Bulk
		AS78L05ZTR-E1	AS78L05ZTR-G1	AS78L05Z-E1	AS78L05Z-G1	Ammo
		AS78L05CZTR-E1	AS78L05CZTR-G1	AS78L05Z-E1	AS78L05Z-G1	Ammo
		AS78L12Z-E1	AS78L12Z-G1	AS78L12Z-E1	AS78L12Z-G1	Bulk
		AS78L12ZTR-E1	AS78L12ZTR-G1	AS78L12Z-E1	AS78L12Z-G1	Ammo
		AS78L15Z-E1	AS78L15Z-G1	AS78L15Z-E1	AS78L15Z-G1	Bulk
SOT-89	-40 to 125°C	AS78L15ZTR-E1	AS78L15ZTR-G1	AS78L15Z-E1	AS78L15Z-G1	Ammo
		AS78L05RTR-E1	AS78L05RTR-G1	E78E	G78E	Tape & Reel
		AS78L12RTR-E1	AS78L12RTR-G1	E78F	G78F	Tape & Reel
SOIC-8	-40 to 125°C	AS78L15RTR-E1	AS78L15RTR-G1	E78G	G78G	Tape & Reel
		AS78L05M-E1	AS78L05M-G1	AS78L05M-E1	AS78L05M-G1	Tube
		AS78L05MTR-E1	AS78L05MTR-G1	AS78L05M-E1	AS78L05M-G1	Tape & Reel
		AS78L12M-E1	AS78L12M-G1	AS78L12M-E1	AS78L12M-G1	Tube
		AS78L12MTR-E1	AS78L12MTR-G1	AS78L12M-E1	AS78L12M-G1	Tape & Reel
		AS78L15M-E1	AS78L15M-G1	AS78L15M-E1	AS78L15M-G1	Tube
		AS78L15MTR-E1	AS78L15MTR-G1	AS78L15M-E1	AS78L15M-G1	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.

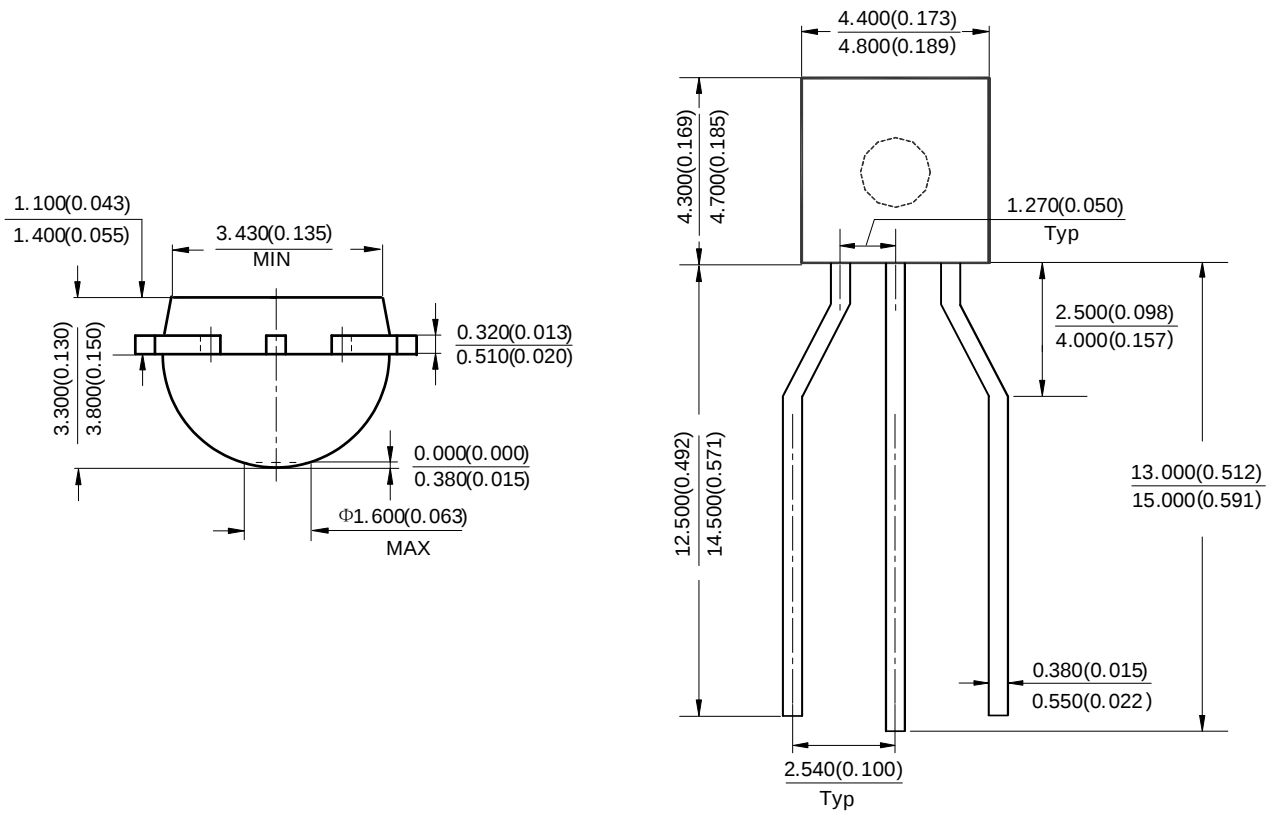
Package Outline Dimensions (All dimensions in mm(inch).)

TO-92 (Bulk Packing)



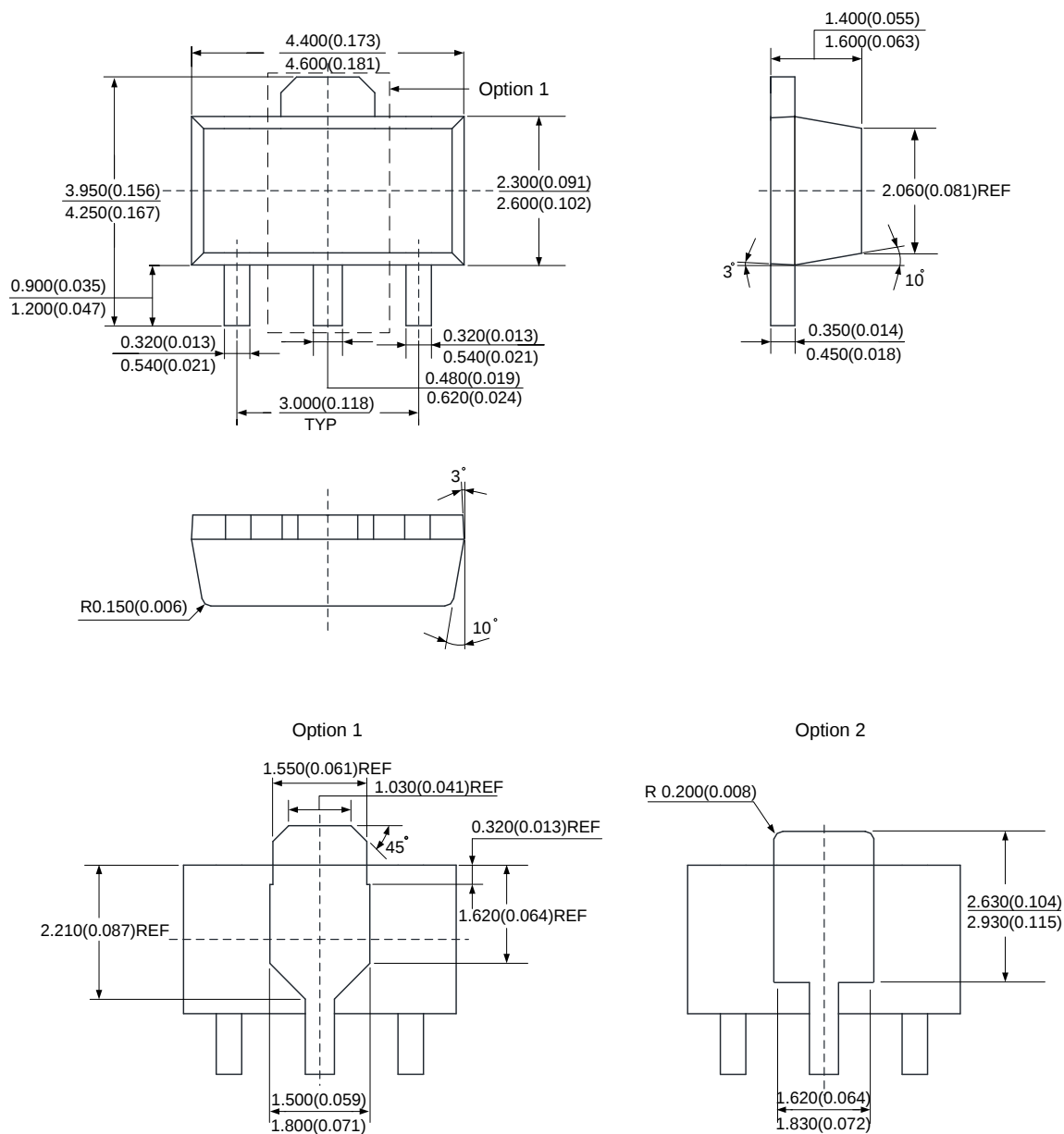
Package Outline Dimensions (cont.) (All dimensions in mm(inch).)

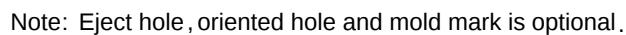
TO-92 (Ammo Packing)



Package Outline Dimensions (cont.) (All dimensions in mm(inch).)

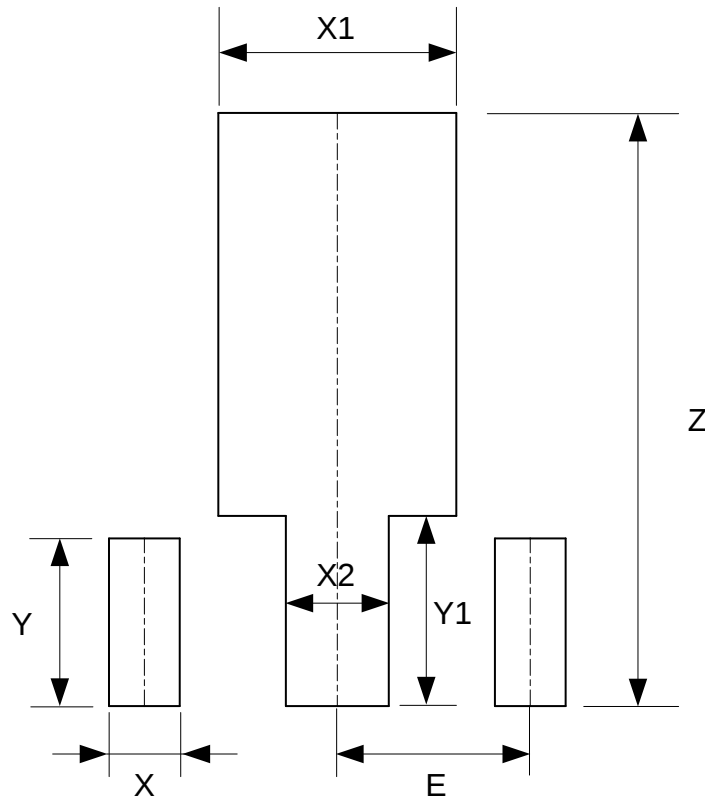
SOT-89



SOIC-8

Suggested Pad Layout

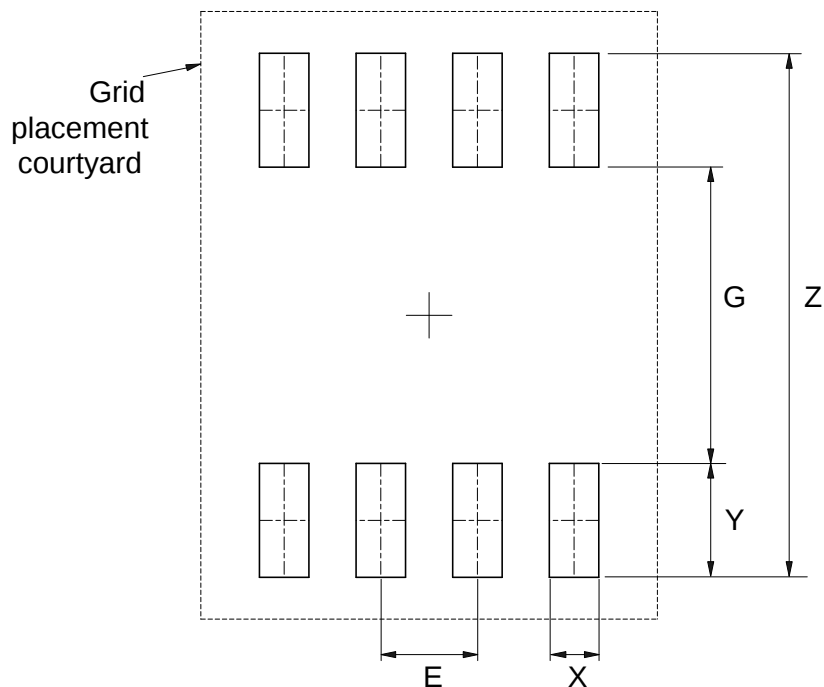
SOT-89



Dimensions	Z (mm)/(inch)	X (mm)/(inch)	X1 (mm)/(inch)	X2 (mm)/(inch)	Y (mm)/(inch)	Y1 (mm)/(inch)	E (mm)/(inch)
Value	4.600/0.181	0.550/0.022	1.850/0.073	0.800/0.031	1.300/0.051	1.475/0.058	1.500/0.059

Suggested Pad Layout (cont.)

SOIC-8



Dimensions	Z (mm)/(inch)	G (mm)/(inch)	X (mm)/(inch)	Y (mm)/(inch)	E (mm)/(inch)
Value	6.900/0.272	3.900/0.154	0.650/0.026	1.500/0.059	1.270/0.050

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